

100V N-Channel Enhancement Mode MOSFET

Voltage	100 V	R _{DSON}	8.2 mΩ
Current	76 A	Q _G (TYP)	28.5 nC

Feature

- R_{DSON} < 8.2 mΩ at V_{GS} = 10 V, I_D = 35 A
- R_{DSON} < 12.5 mΩ at V_{GS} = 4.5 V, I_D = 17.5 A
- High switching speed
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

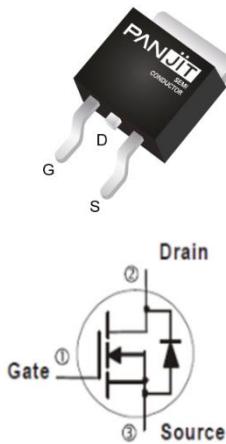
Mechanical Data

- Case: TO-252AA molded plastic
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.3217 grams

Application

- SR solutions of Monitor PSU/ TV PSU .

TO-252AA



Top side view

Absolute Maximum Ratings (T_A = 25 °C unless otherwise specified)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Voltage	V _{GS}	±20	
Continuous Drain Current (Note 3)	I _D	76	A
T _C =25 °C		54	
T _C =100 °C			
Pulsed Drain Current	I _{DM}	304	A
T _C =25 °C			
Single Pulse Avalanche Current (Note 5)	I _{AS}	15	A
Single Pulse Avalanche Energy (Note 5)	E _{AS}	48	mJ
Power Dissipation	P _D	100	W
T _C =25 °C		50	
T _C =100 °C			
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55~175	°C

Thermal Characteristics

PARAMETER	SYMBOL	VALUES			UNITS
		MIN.	TYP.	MAX.	
Thermal Resistance	Junction-to-Case (Bottom)	R _{θJC}	-	1.0	1.5 °C/W
	Junction-to-Ambient (Note 4)	R _{θJA}	-	-	50 °C/W

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0 \text{ V}, I_{\text{D}}=250 \mu\text{A}$	100	-	-	V
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=135 \mu\text{A}$	1.1	1.7	2.3	
Drain-Source On-State Resistance ^(Note 1)	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}}=10 \text{ V}, I_{\text{D}}=35 \text{ A}$	-	7.3	8.2	$\text{m}\Omega$
		$V_{\text{GS}}=4.5 \text{ V}, I_{\text{D}}=17.5 \text{ A}$	-	9.5	12.5	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=100 \text{ V}, V_{\text{GS}}=0 \text{ V}$	-	-	1	μA
Gate-Source Leakage Current	I_{GS}	$V_{\text{GS}}=\pm 20 \text{ V}, V_{\text{DS}}=0 \text{ V}$	-	-	± 100	nA
Transfer characteristics ^(Note 1)	g_{fs}	$V_{\text{DS}}=10 \text{ V}, I_{\text{D}}=35 \text{ A}$	-	90	-	S
Dynamic Characteristics ^(Note 6)						
Total Gate Charge	Q_g	$V_{\text{DS}}=50 \text{ V}, I_{\text{D}}=35 \text{ A}, V_{\text{GS}}=4.5 \text{ V}$	-	14	-	nC
Gate-Source Charge	Q_{gs}		-	28.5	37	nC
Gate-Drain Charge	Q_{gd}		-	5.5	-	
Gate Plateau Voltage	V_{plateau}		-	3.8	-	
Input Capacitance	C_{iss}		-	3.0	-	V
Output Capacitance	C_{oss}	$V_{\text{DS}}=50 \text{ V}, V_{\text{GS}}=0 \text{ V}, f=250 \text{ kHz}$	-	1770	2300	pF
Reverse Transfer Capacitance	C_{rss}		-	610	800	
Output Charge	Q_{oss}		-	12	-	
Turn-On Delay Time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}}=50 \text{ V}, I_{\text{D}}=35 \text{ A}, V_{\text{GS}}=10 \text{ V}, R_{\text{G}}=3.0 \Omega$ ^(Note 2)	-	42	55	nC
Rise Time	t_r		-	7.2	-	ns
Turn-Off Delay Time	$t_{\text{d}(\text{off})}$		-	3.5	-	
Fall Time	t_f		-	20	-	
Gate Resistance	R_g	$f=1.0 \text{ MHz}$	-	3.5	-	
Drain-Source Diode						
Diode Forward Voltage	V_{SD}	$I_{\text{S}}=35 \text{ A}, V_{\text{GS}}=0 \text{ V}$	-	0.9	1.2	V
Reverse Recovery Charge	Q_{rr}	$I_{\text{F}}=35 \text{ A}, V_{\text{DD}}=50 \text{ V},$ $dI/dt=100 \text{ A}/\mu\text{s}$	-	76	-	nC
Reverse Recovery Time	T_{rr}		-	53	-	ns

NOTES :

1. Pulse width $\leq 300 \mu\text{s}$, Duty cycle $\leq 2 \%$.
2. Essentially independent of operating temperature typical characteristics.
3. The maximum drain current calculated by maximum junction temperature and thermal impedance. It can be varied by application and environment.
4. $R_{\theta\text{JA}}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
5. E_{AS} is calculated based on the condition by $L=1\text{mH}$, $I_{\text{AS}}=9.8\text{A}$, and then $L = 0.1 \text{ mH}$, $I_{\text{AS}} = 15 \text{ A}$, $V_{\text{DD}} = 50 \text{ V}$, $V_{\text{GS}} = 10 \text{ V}$. 100% test in production.
6. Guaranteed by design, not subject to production testing.

TYPICAL CHARACTERISTIC CURVES

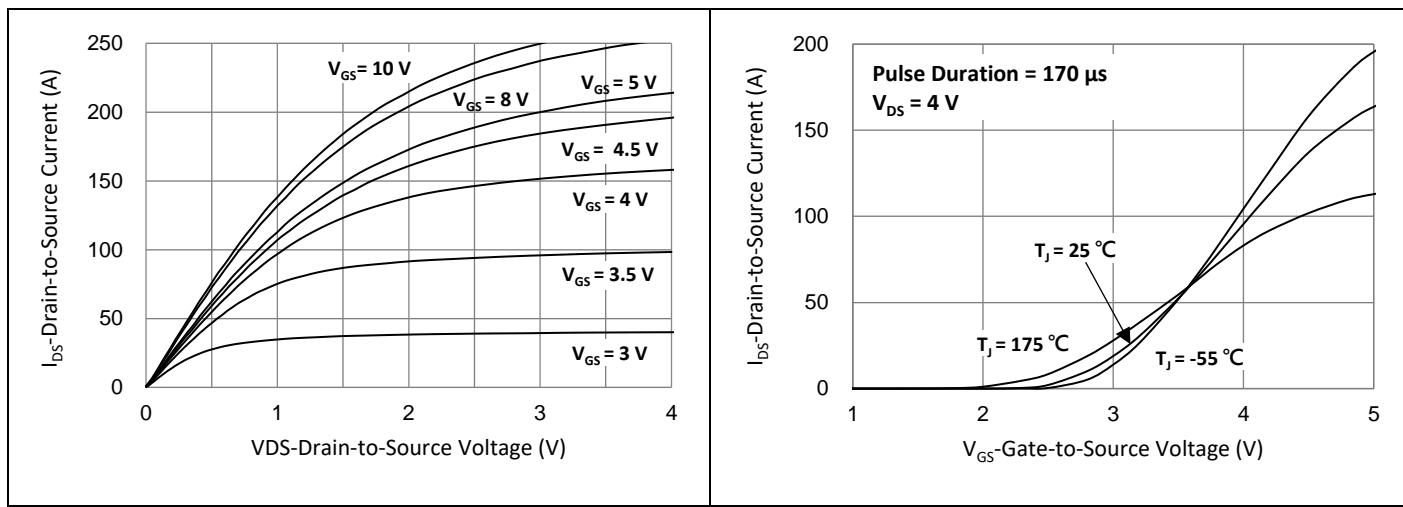


Fig.1 Output Characteristics

Fig.2 Transfer Characteristics

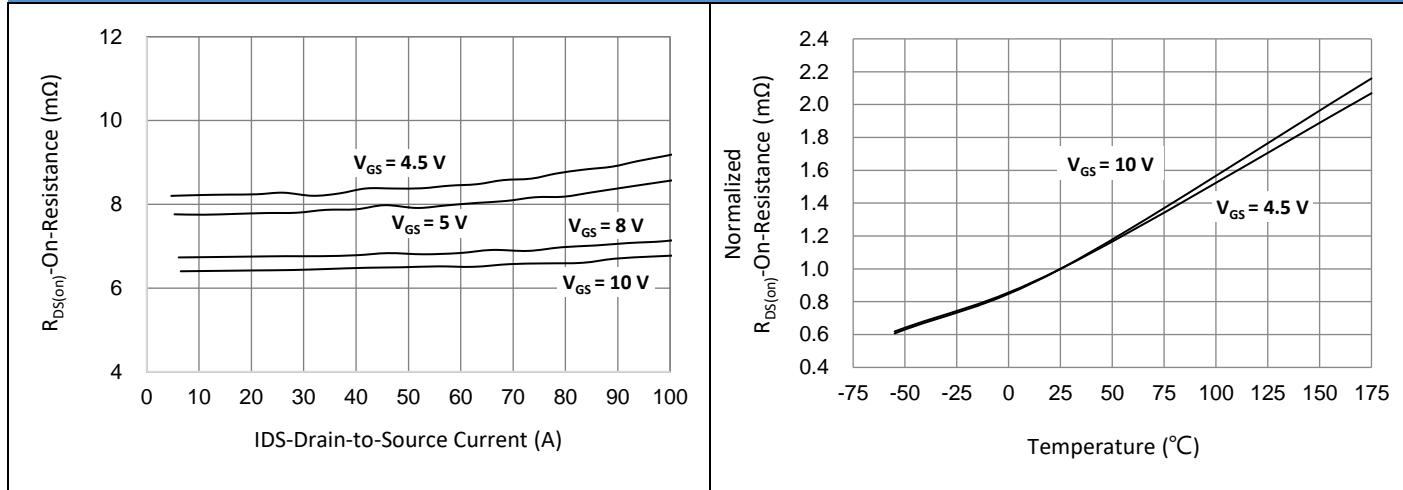


Fig.3 On-Resistance vs. Drain Current

Fig.4 On-Resistance vs. Junction temperature

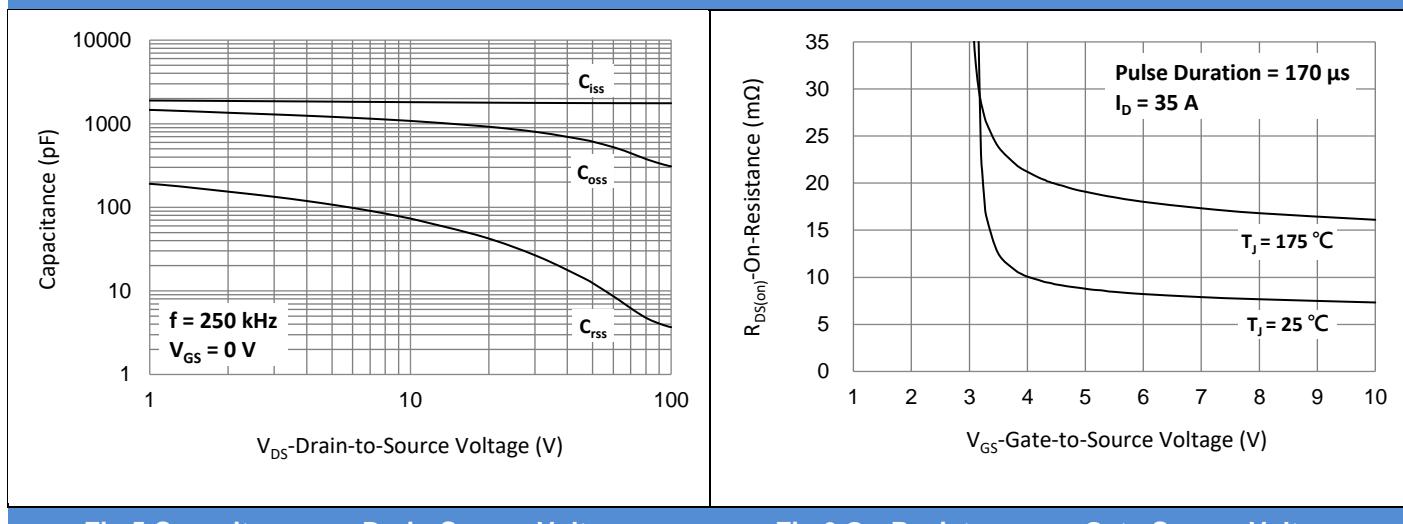


Fig.5 Capacitance vs. Drain-Source Voltage

Fig.6 On-Resistance vs. Gate-Source Voltage

TYPICAL CHARACTERISTIC CURVES

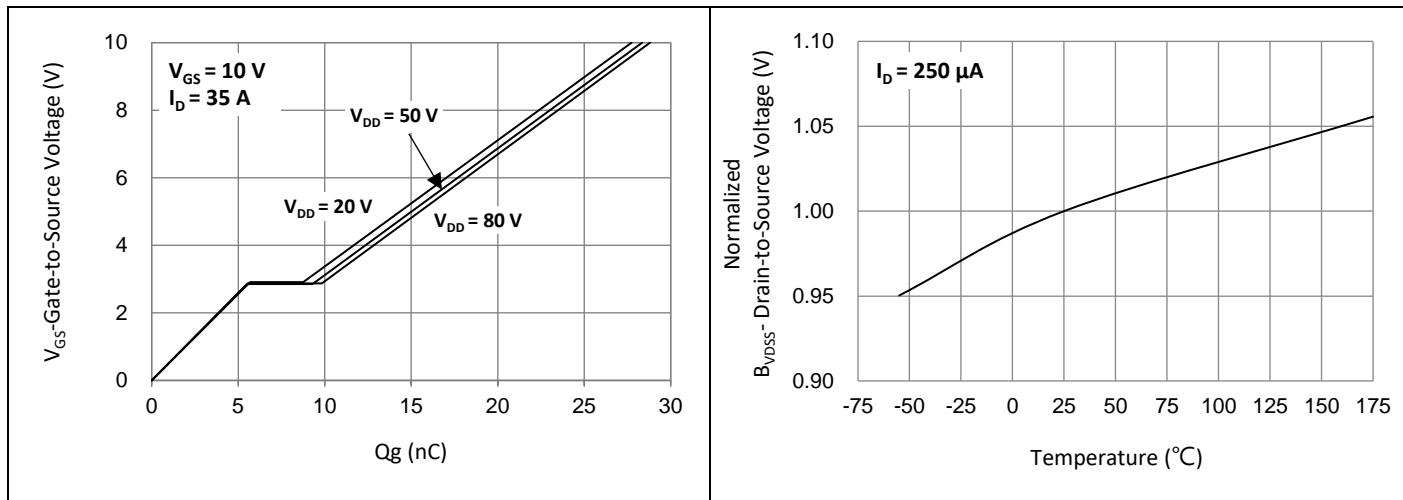


Fig.8 Breakdown Voltage Variation vs. Temperature

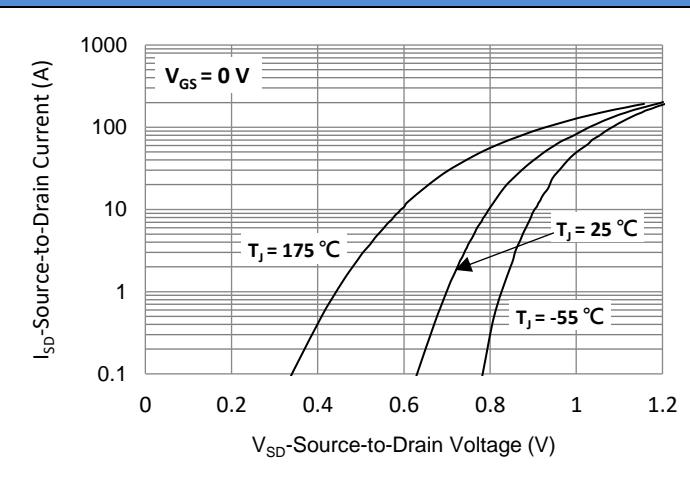


Fig.9 Threshold Voltage Variation with Temperature

Fig.10 Source-Drain Diode Forward Voltage

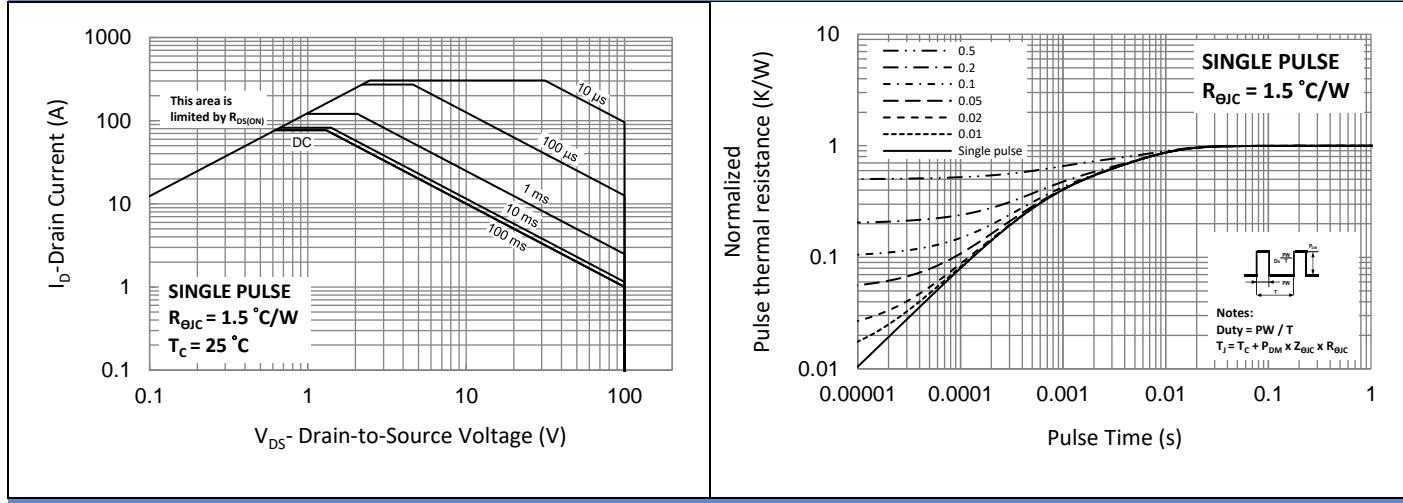


Fig.10 Source-Drain Diode Forward Voltage

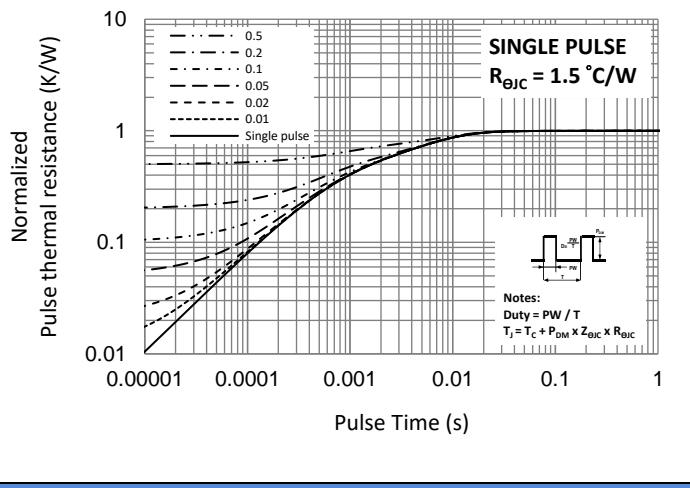


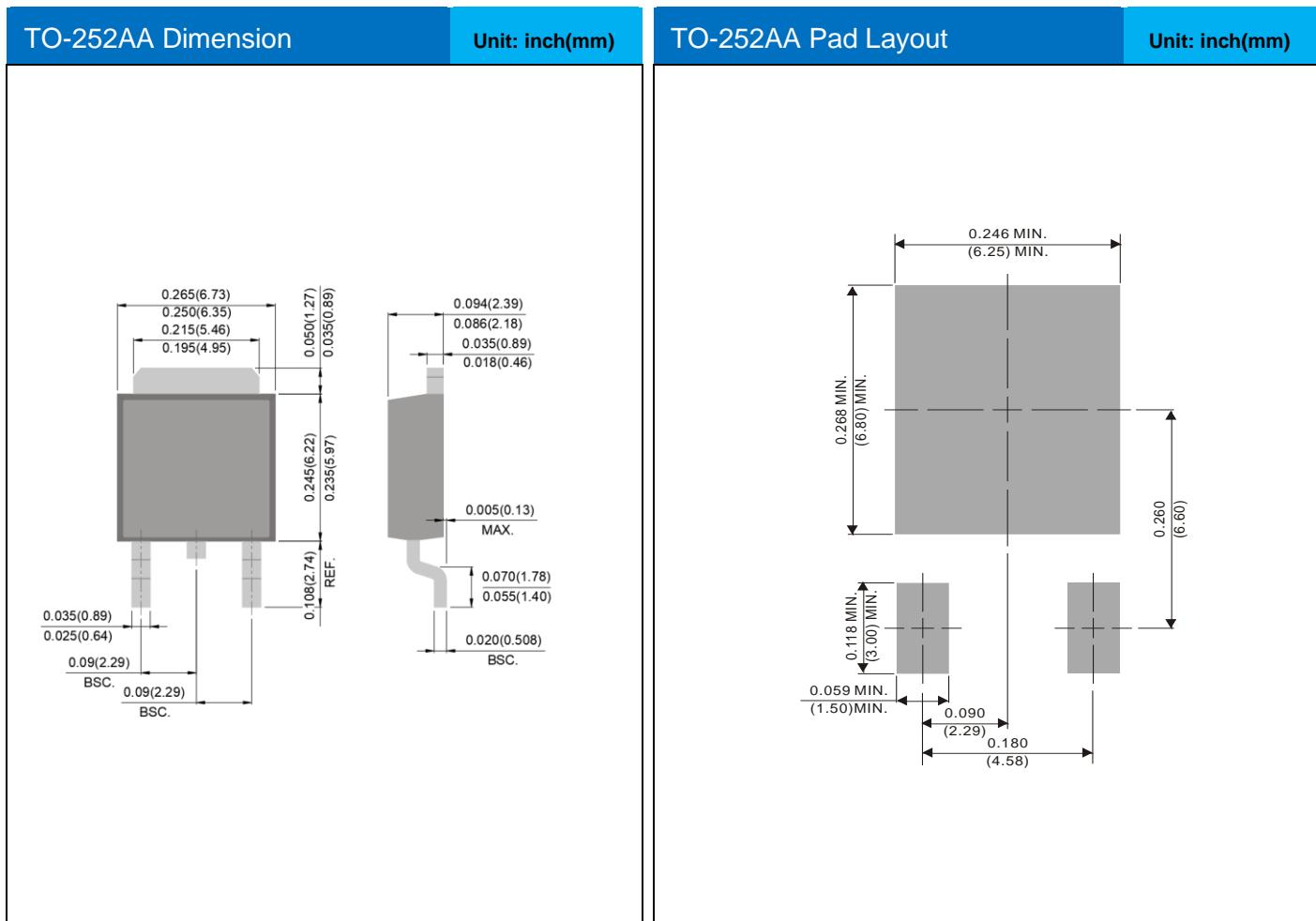
Fig.11 Maximum Safe Operating Area

Fig.12 Normalized Transient Thermal Impedance

Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PSMD081N10LS2	TO-252AA	3,000 pcs / 13" reel	081N10LS

Packaging Information & Mounting Pad Layout



Marking Diagram

PJ
081N10LS
YWLL X

Y = Year Code
W = Week Code (A~Z)
LL = Lot Code (00~99)
x = Production Line Code

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